

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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HTZ130B Series

 $I_{F(AV)} = 1.0 A$

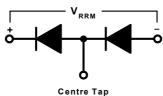
 $V_{RRM} = 38000 \text{ V}$

High Voltage Diode Rectifier Module

LARONTROL

Electronic Devices

Type Number	Repetitive Peak	Minimum Avalanche Voltage V _{(BR)R}
HTZ130B38K HTZ130B33K HTZ130B28K HTZ130B24K	38000 33000 28000 24000	40800 36000 31200 26400
CIRCUIT DIAGRA	γW,	/ _{RRM}





CURRENT RATINGS - AIR COOLED

I _{F(AV)}	Mean forward current	Half wave resistive load T _{amb} = 35°C	1.0	Α
l _F `	Continuous (direct) forward current	$T_{amb} = 35^{\circ}C$	1.2	Α
$R_{\text{th(j-a)}}$	Thermal resistance junction to ambient		5.7	°C/W

CURRENT RATINGS - OIL COOLED

I _{F(AV)}	Mean forward current	Half wave resistive load T _{oil} = 60°C	3.1	Α
I _T `´	Continuous (direct) forward current	$T_{oil} = 60$ °C	3.6	Α
$R_{th(j-o)}$	Thermal resistance junction to oil		1.2	°C/W

SURGE RATINGS

l²t	I ² t for fusing	10 ms half sine T _{vi} = 150°C	50 A ²	² sec
I _{FSM}	Surge (non-repetitive) forward current	T _{vj} = 150°C	100	Α

TEMPERATURE AND FREQUENCY RATINGS

I I IVII I	INATORE AND TREGOENCY RATING	.		
T_{vi}	Virtual junction temperature	Forward (conducting)	180	°C
•		Reverse (blocking)	180	°C
T_{stg}	Storage temperature range		-40 to 100	°C
f	Frequency range		20 to 400	Hz

CHARACTERISTICS $T_{case} = 25^{\circ}C$ unless otherwise stated

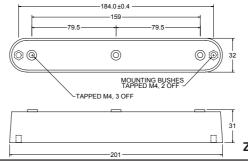
$V_{\sf FM}$	Forward voltage	At 2 Amps peak	max 24.0	V
I _{RM}	Peak reverse current	At V_{RRM} ; $T_{case} = 150$ °C	max 0.5	mΑ

Dimensioned Outlines

Dimensions shown are maximum in mm

IXYS reserves the right to change limits, test conditions and dimensions.

Weight typ.: 0,38 Kg



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V_{RRM} = 38000 V

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